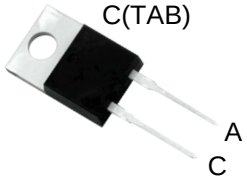
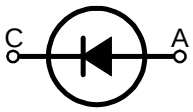
HUR1560

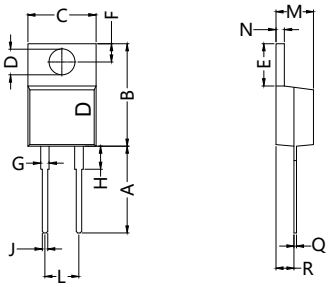
Soft Recovery Behaviour High-Performance Wide Temperature Range Ultra Fast Recovery Epitaxial Diodes





A=Anode, C=Cathode, TAB=Cathode

Dimensions TO-220AC



Dim.	Millimeter	
	Min.	Max.
A	12.70	13.97
B	14.73	16.00
C	9.91	10.66
ØD	3.54	4.08
E	5.85	6.85
F	2.54	3.18
G	1.15	1.65
H	2.79	5.84
J	0.64	1.01
L	5.05BSC	
M	4.32	4.82
N	1.14	1.39
Q	0.35	0.56
R	2.29	2.79

	V_{RSM} V	V_{RRM} V
HUR1560	600	600

Symbol	Test Conditions	Maximum Ratings	Unit
I_{FRMS} I_{FAVM}	T_C=140°C; rectangular, d=0.5	35 15	A
I_{FSM}	T_{VJ}=45°C; t_p=10ms (50Hz), sine	110	A
E_{AS}	T_{VJ}=25°C; non-repetitive; I_{AS}=1A; L=180uH	0.1	mJ
I_{AR}	V_A=1.5·V_R typ.; f=10kHz; repetitive	0.1	A
T_{VJ} T_{VJM} T_{stg}		-55...+175 175 -55...+150	°C
P_{tot}	T_C=25°C	95	W
M_d	mounting torque	0.4...0.6	Nm
Weight	typical	2	g

www.sirectifier.com Tel: +86-519-86800000 Fax: +86-519-88019019 E-mail: sales@sirectifier.com

HUR1560

Soft Recovery Behaviour High-Performance Wide Temperature Range Ultra Fast Recovery Epitaxial Diodes

Symbol	Test Conditions	Characteristic Values		Unit
		typ.	max.	
I_R	T_{VJ}=25°C; V_R=V_{RRM} T_{VJ}=150°C; V_R=V_{RRM}		100 0.5	uA mA
V_F	I_F=15A; T_{VJ}=150°C T_{VJ}=25°C	1.15 1.30	1.25 1.55	V
R_{thJC} R_{thCH}		 0.4	2.5	K/W
t_{rr}	I_F=1A; -di/dt=100A/us; V_R=30V; T_{VJ}=25°C	35		ns
I_{RM}	V_R=100V; I_F=25A; -di$_F$/dt=100A/us; T_{VJ}=100°C		4.9	A

FEATURES

* International standard package
* Planar passivated chips
* Very short recovery time
* Extremely low switching losses
* Low I_{RM}-values
* Soft recovery behaviour
* RoHS compliant

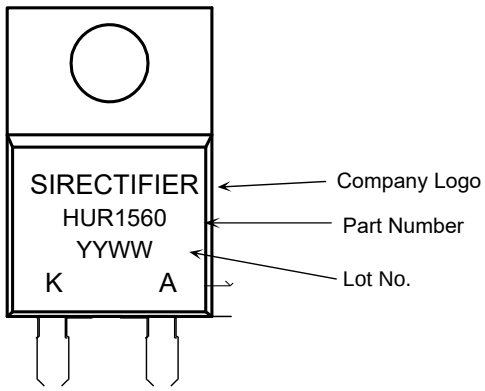
APPLICATIONS

* Antiparallel diode for high frequency switching devices
* Antisaturation diode
* Snubber diode
* Free wheeling diode in converters and motor control circuits
* Rectifiers in switch mode power supplies (SMPS)
* Inductive heating
* Uninterruptible power supplies (UPS)
* Ultrasonic cleaners and welders

ADVANTAGES

* Avalanche voltage rated for reliable operation
* Soft reverse recovery for low EMI/RFI
* Low I_{RM} reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

Marking



Ordering Information

Part Number	Package	Shipping	Marking Code
HUR1560	TO-220AC	50pcs / Tube	HUR1560

www.sirectifier.com Tel: +86-519-86800000 Fax: +86-519-88019019 E-mail: sales@sirectifier.com

HUR1560

Soft Recovery Behaviour High-Performance Wide Temperature Range Ultra Fast Recovery Epitaxial Diodes

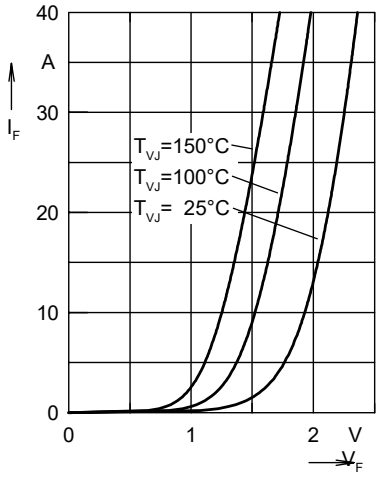


Fig. 1 Forward current I_F versus V_F

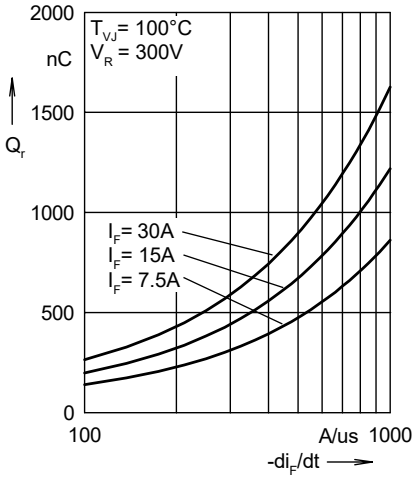


Fig. 2 Reverse recovery charge Q_r versus $-di_F/dt$

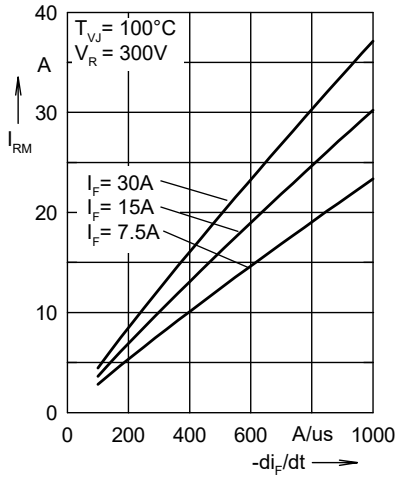


Fig. 3 Peak reverse current I_{RM} versus $-di_F/dt$

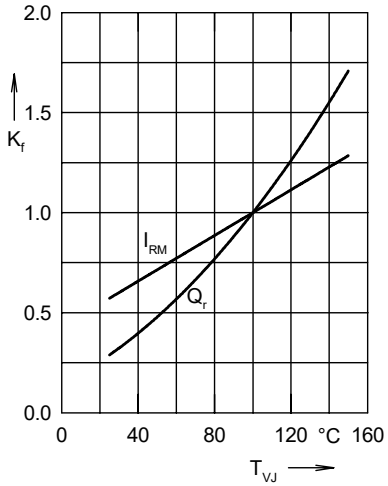


Fig. 4 Dynamic parameters Q_r, I_{RM} versus T_{VJ}

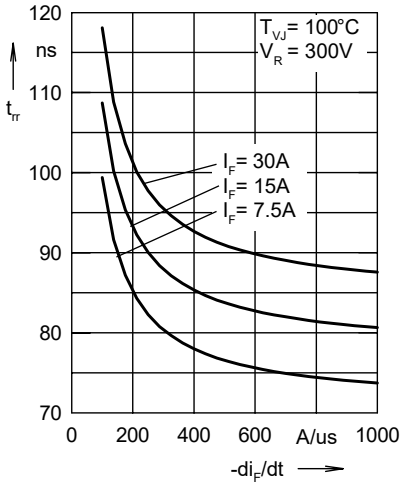


Fig. 5 Recovery time t_{rr} versus $-di_F/dt$

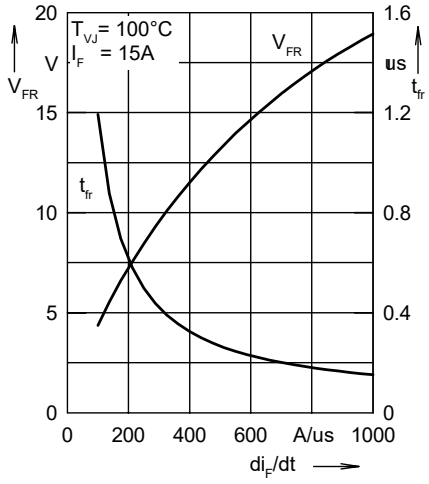


Fig. 6 Peak forward voltage V_{FR} and t_{fr} versus di_F/dt

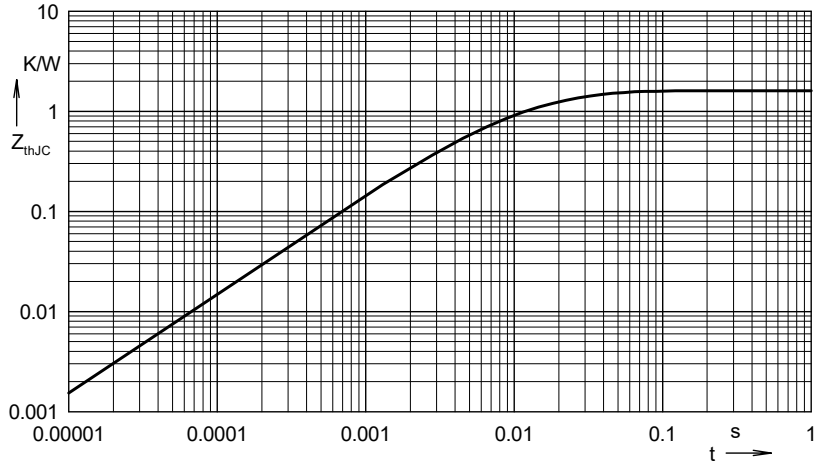


Fig. 7 Transient thermal resistance junction to case

Constants for Z_{thJC} calculation:

i	R_{thi}(K/W)	t_i (s)
1	0.908	0.0052
2	0.35	0.0003
3	0.342	0.017

www.sirectifier.com Tel: +86-519-86800000 Fax: +86-519-88019019 E-mail: sales@sirectifier.com